NSN 5962-01-108-7869

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View Online at https://aerobasegroup.com/nsn/5962-01-108-7869 **Body Length:** Between 0.750 inches and 0.795 inches **Body Width:** Between 0.245 inches and 0.300 inches **Body Height:** Between 0.120 inches and 0.195 inches **Maximum Power Dissipation Rating:** 512.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and programmable and programmed and bipolar and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** Mo-001-ag joint electron device engineering council **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 13499-351-7769 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Yes - demil/mli

Demilitarization:

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